## FEATURES

Latch-up immune under all circumstances Human body model (HBM) ESD rating: $\mathbf{8 k V}$<br>Low on resistance: $6.5 \Omega$<br>$\pm 9 \mathrm{~V}$ to $\pm 22 \mathrm{~V}$ dual-supply operation<br>9 V to 40 V single-supply operation<br>48 V supply maximum ratings<br>Fully specified at $\pm 15 \mathrm{~V}, \pm 20 \mathrm{~V},+12 \mathrm{~V}$, and $+\mathbf{3 6} \mathrm{V}$<br>$\mathrm{V}_{\mathrm{DD}}$ to $\mathrm{V}_{\mathrm{SS}}$ analog signal range

## APPLICATIONS

High voltage signal routing
Automatic test equipment
Analog front-end circuits
Precision data acquisition
Amplifier gain select
Industrial instrumentation

## Relay replacement

## GENERAL DESCRIPTION

The ADG5401 is a monolithic industrial, complementary metal oxide semiconductor (CMOS) analog switch containing a latchup immune single-pole/single-throw (SPST) switch. The switch conducts equally well in both directions when on, and has an input signal range that extends to the power supplies. In the off condition, signal levels up to the supplies are blocked.

The ultralow on resistance and on-resistance flatness of these switches make them ideal solutions for data acquisition and gain switching applications, where low distortion is critical. The latch-up immune construction and high ESD rating make these switches more robust in harsh environments.

## FUNCTIONAL BLOCK DIAGRAM



SWITCHES SHOWN FOR A LOGIC 1 INPUT
Figure 1.

## PRODUCT HIGHLIGHTS

1. Trench isolation guards against latch-up. A dielectric trench separates the P channel and N channel transistors, thereby preventing latch-up even under severe overvoltage conditions.
2. Low Ron of $6.5 \Omega$.
3. Dual-supply operation. For applications where the analog signal is bipolar, the ADG5401 can operate from dual supplies of up to $\pm 22 \mathrm{~V}$.
4. Single-supply operation. For applications where the analog signal is unipolar, the ADG5401 can operate from a singlerail power supply of up to 40 V .
5. 3 V logic compatible digital inputs: $\mathrm{V}_{\mathrm{INH}}=2.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{INL}}=0.8 \mathrm{~V}$.
6. No $V_{L}$ logic power supply required.
7. Available in 8-lead MSOP package.

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## REVISION HISTORY

9/13-Revision 0: Initial Version

## SPECIFICATIONS

## $\pm 15$ V DUAL SUPPLY

$\mathrm{V}_{\mathrm{DD}}=+15 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=-15 \mathrm{~V} \pm 10 \%$, GND $=0 \mathrm{~V}$, unless otherwise noted.
Table 1.

| Parameter | $25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH <br> Analog Signal Range On Resistance, Ron On-Resistance Flatness, Rflat (on) | $\begin{aligned} & 6.5 \\ & 8 \\ & 1 \\ & 1.4 \end{aligned}$ | 10 1.7 | VDD to $V_{S S}$ <br> 12 <br> 2 | V <br> $\Omega$ typ <br> $\Omega$ max <br> $\Omega$ typ <br> $\Omega$ max | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}= \pm 10 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=-10 \mathrm{~mA} \text {; see Figure } 19 \\ & \mathrm{~V}_{\mathrm{DD}}=+13.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-13.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}= \pm 10 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=-10 \mathrm{~mA} \end{aligned}$ |
| LEAKAGE CURRENTS <br> Source Off Leakage, Is (Off) <br> Drain Off Leakage, lo (Off) <br> Channel On Leakage, $\mathrm{I}_{\mathrm{D}}(\mathrm{On})$, $\mathrm{I}_{\mathrm{s}}(\mathrm{On})$ | $\begin{aligned} & \pm 0.1 \\ & \pm 0.5 \\ & \pm 0.1 \\ & \pm 0.5 \\ & \pm 0.2 \\ & \pm 1 \end{aligned}$ | $\begin{aligned} & \pm 2 \\ & \pm 2 \\ & \pm 8 \end{aligned}$ | $\begin{aligned} & \pm 20 \\ & \pm 20 \\ & \pm 40 \end{aligned}$ | nA typ <br> nA max <br> nA typ <br> nA max <br> nA typ <br> nA max | $\begin{aligned} & V_{D D}=+16.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-16.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}= \pm 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=\mp 10 \mathrm{~V} \text {; see Figure } 18 \\ & \mathrm{~V}_{\mathrm{S}}= \pm 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=\mp 10 \mathrm{~V} \text {; see Figure } 18 \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}= \pm 10 \mathrm{~V} \text {; see Figure } 21 \end{aligned}$ |
| DIGITAL INPUTS Input High Voltage, $\mathrm{V}_{\mathrm{INH}}$ Input Low Voltage, VINL Input Current, $\mathrm{I}_{\mathrm{NL}}$ or $\mathrm{l}_{\mathrm{INH}}$ Digital Input Capacitance, Cin | $\begin{aligned} & 0.002 \\ & 6 \end{aligned}$ |  | $\begin{aligned} & 2.0 \\ & 0.8 \\ & \pm 0.1 \end{aligned}$ | $\vee$ min <br> $V$ max <br> $\mu A$ typ <br> $\mu \mathrm{A}$ max <br> pF typ | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\mathrm{DD}}$ |
| ```DYNAMIC CHARACTERISTICS ton toff Charge Injection, Qins Off Isolation Total Harmonic Distortion + Noise (THD + N) -3 dB Bandwidth Insertion Loss Cs (Off) CD (Off) CD (On), CS (On)``` | 160 193 175 207 220 -50 0.01 170 -0.4 22 24 75 | $\begin{aligned} & 230 \\ & 230 \end{aligned}$ | $\begin{aligned} & 253 \\ & 242 \end{aligned}$ | $\begin{aligned} & \text { ns typ } \\ & \text { ns max } \\ & \text { ns typ } \\ & \text { ns max } \\ & \text { pC typ } \\ & \text { dB typ } \\ & \text { \% typ } \\ & \text { MHz typ } \\ & \text { dB typ } \\ & \text { pF typ } \\ & \text { pF typ } \\ & \text { pF typ } \end{aligned}$ | $\begin{aligned} & R_{L}=300 \Omega, C_{L}=35 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{S}}=10 \mathrm{~V} ; \text { see Figure } 24 \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, C_{\mathrm{L}}=35 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{S}}=10 \mathrm{~V} ; \text { see Figure } 24 \\ & \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=0 \Omega, C_{\mathrm{L}}=1 \mathrm{nF} ; \text { see } \end{aligned}$ <br> Figure 25 <br> $R \mathrm{~L}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; see <br> Figure 20 <br> $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, 15 \mathrm{~V}$ p-p, $\mathrm{f}=20 \mathrm{~Hz}$ to <br> 20 kHz; see Figure 22 <br> $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$; see Figure 23 <br> $R_{L}=50 \Omega, C_{L}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; <br> see Figure 23 <br> $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ <br> $V_{s}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ <br> $\mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| POWER REQUIREMENTS IDD Iss $V_{D D} / V_{S S}$ | $\begin{aligned} & 45 \\ & 55 \\ & 0.001 \end{aligned}$ |  | 70 <br> 1 $\pm 9 / \pm 22$ | $\mu A$ typ <br> $\mu \mathrm{A}$ max <br> $\mu \mathrm{A}$ typ <br> $\mu \mathrm{A}$ max <br> $V \min / V \max$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=+16.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-16.5 \mathrm{~V} \\ & \text { Digital inputs }=0 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{DD}} \\ & \text { Digital inputs }=0 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{DD}} \\ & \text { GND }=0 \mathrm{~V} \end{aligned}$ |

[^0]
## ADG5401

## $\pm 20$ V DUAL SUPPLY

$\mathrm{V}_{\mathrm{DD}}=+20 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=-20 \mathrm{~V} \pm 10 \%, \mathrm{GND}=0 \mathrm{~V}$, unless otherwise noted.
Table 2.

| Parameter | $25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH <br> Analog Signal Range On Resistance, Ron <br> On-Resistance Flatness, Rflat (on) | $\begin{aligned} & 6 \\ & 7 \\ & 7 \\ & 1.2 \\ & 1.7 \\ & \hline \end{aligned}$ | 9 2.1 | $V_{D D}$ to $V_{S S}$ <br> 11 <br> 2.5 | V <br> $\Omega$ typ <br> $\Omega$ max <br> $\Omega$ typ <br> $\Omega$ max | $\mathrm{V}_{\mathrm{s}}= \pm 15 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA} ;$ <br> see Figure 19 $\begin{aligned} & V_{D D}=+18 \mathrm{~V}, \mathrm{~V}_{S S}=-18 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}= \pm 15 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=-10 \mathrm{~mA} \end{aligned}$ |
| LEAKAGE CURRENTS <br> Source Off Leakage, Is (Off) <br> Drain Off Leakage, ID (Off) <br> Channel On Leakage, $\mathrm{I}_{\mathrm{D}}(\mathrm{On}), \mathrm{I}_{\mathrm{s}}(\mathrm{On})$ | $\begin{aligned} & \pm 0.1 \\ & \pm 0.5 \\ & \pm 0.1 \\ & \pm 0.5 \\ & \pm 0.2 \\ & \pm 1 \end{aligned}$ | $\pm 2$ <br> $\pm 2$ <br> $\pm 8$ | $\begin{aligned} & \pm 20 \\ & \pm 20 \\ & \pm 40 \end{aligned}$ | nA typ <br> nA max <br> nA typ <br> nA max <br> nA typ <br> nA max | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=+22 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-22 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=\mp 15 \mathrm{~V} ; \text { see } \end{aligned}$ <br> Figure 18 $V_{S}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=\mp 15 \mathrm{~V} \text {; see }$ <br> Figure 18 $\mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}= \pm 15 \mathrm{~V} \text {; see Figure } 21$ |
| DIGITAL INPUTS <br> Input High Voltage, Vinh <br> Input Low Voltage, VinL <br> Input Current, $\mathrm{I}_{\mathrm{INL}}$ or $\mathrm{I}_{\mathrm{NH}}$ <br> Digital Input Capacitance, Cin | $\begin{aligned} & 0.002 \\ & 6 \end{aligned}$ |  | $\begin{gathered} 2.0 \\ 0.8 \\ \pm 0.1 \end{gathered}$ | $V$ min <br> $V$ max <br> $\mu A$ typ <br> $\mu \mathrm{A}$ max <br> pF typ | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\mathrm{DD}}$ |
| ```DYNAMIC CHARACTERISTICS ton toff Charge Injection, Qins Off Isolation Total Harmonic Distortion + Noise (THD + N) -3 dB Bandwidth Insertion Loss Cs (Off) CD (Off) CD (On), Cs (On)``` | 150 175 170 196 275 -50 0.01 170 -0.5 21 23 75 | $\begin{aligned} & 207 \\ & 214 \end{aligned}$ | $\begin{aligned} & 219 \\ & 223 \end{aligned}$ | $\begin{aligned} & \text { ns typ } \\ & \text { ns max } \\ & \text { ns typ } \\ & \text { ns max } \\ & \text { pC typ } \\ & \text { dB typ } \\ & \text { \% typ } \\ & \text { MHz typ } \\ & \text { dB typ } \\ & \text { pF typ } \\ & \text { pF typ } \\ & \text { pF typ } \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{S}}=10 \mathrm{~V} ; \text { see Figure } 24 \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{S}}=10 \mathrm{~V} ; \text { see Figure } 24 \\ & \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=0 \Omega, \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF} \text {; see } \end{aligned}$ <br> Figure 25 <br> $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; see <br> Figure 20 <br> $R_{L}=1 \mathrm{k} \Omega, 20 \mathrm{~V} p-\mathrm{p}, \mathrm{f}=20 \mathrm{~Hz}$ to <br> 20 kHz ; see Figure 22 <br> $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$; see Figure 23 <br> $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; <br> see Figure 23 <br> $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ <br> $V_{s}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ <br> $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| POWER REQUIREMENTS <br> IDD Iss $V_{D D} / V_{S S}$ | $\begin{aligned} & 50 \\ & 70 \\ & 0.001 \end{aligned}$ |  | $110$ <br> 1 $\pm 9 / \pm 22$ | $\mu \mathrm{A}$ typ <br> $\mu \mathrm{A}$ max <br> $\mu \mathrm{A}$ typ <br> $\mu \mathrm{A}$ max <br> $V \min / V \max$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=+22 \mathrm{~V}, \mathrm{~V}_{S S}=-22 \mathrm{~V} \\ & \text { Digital inputs }=0 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{DD}} \\ & \text { Digital inputs }=0 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{DD}} \\ & \text { GND }=0 \mathrm{~V} \end{aligned}$ |

[^1]ADG5401

## 12 V SINGLE SUPPLY

$\mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}$, unless otherwise noted.
Table 3.

| Parameter | $25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH <br> Analog Signal Range On Resistance, Ron <br> On-Resistance Flatness, Rflat (on) | $\begin{aligned} & 14 \\ & 16 \\ & 2.8 \\ & 4 \end{aligned}$ | 19 <br> 5.5 | 0 V to $\mathrm{V}_{\mathrm{DD}}$ <br> 22 <br> 7 | V <br> $\Omega$ typ <br> $\Omega$ max <br> $\Omega$ typ <br> $\Omega$ max | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V} \text { to } 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA} \text {; see }$ <br> Figure 19 $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=10.8 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V} \text { to } 10 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=-10 \mathrm{~mA} \end{aligned}$ |
| LEAKAGE CURRENTS <br> Source Off Leakage, Is (Off) <br> Drain Off Leakage, lo (Off) <br> Channel On Leakage, $\mathrm{I}_{\mathrm{D}}(\mathrm{On}), \mathrm{I}_{\mathrm{s}}(\mathrm{On})$ | $\begin{aligned} & \pm 0.1 \\ & \pm 0.5 \\ & \pm 0.1 \\ & \pm 0.5 \\ & \pm 0.2 \\ & \pm 1 \end{aligned}$ | $\pm 2$ $\pm 2$ $\pm 8$ | $\begin{aligned} & \pm 20 \\ & \pm 20 \\ & \pm 40 \end{aligned}$ | nA typ <br> nA max <br> nA typ <br> nA max <br> nA typ <br> nA max | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=+13.2 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=1 \mathrm{~V} \text { to } 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=10 \mathrm{~V} \text { to } 1 \mathrm{~V} ; \end{aligned}$ <br> see Figure 18 <br> $\mathrm{V}_{\mathrm{s}}=1 \mathrm{~V}$ to $10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=10 \mathrm{~V}$ to 1 V ; <br> see Figure 18 <br> $V_{S}=V_{D}=1 \mathrm{~V}$ to 10 V ; see Figure 21 |
| DIGITAL INPUTS Input High Voltage, $\mathrm{V}_{\mathrm{INH}}$ Input Low Voltage, VinL Input Current, $\mathrm{I}_{\mathrm{NL}}$ or $\mathrm{I}_{\mathrm{INH}}$ <br> Digital Input Capacitance, $\mathrm{C}_{\mathrm{IN}}$ | $\begin{aligned} & 0.002 \\ & 6 \end{aligned}$ |  | $\begin{gathered} 2.0 \\ 0.8 \\ \pm 0.1 \end{gathered}$ | $V$ min <br> V max <br> $\mu A$ typ <br> $\mu \mathrm{A}$ max <br> pF typ | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\text {DD }}$ |
| ```DYNAMIC CHARACTERISTICS ton toff Charge Injection, QiNs Off Isolation Total Harmonic Distortion + Noise (THD + N) -3 dB Bandwidth Insertion Loss Cs(Off) CD (Off) CD (On), CS (On)``` | 260 327 200 244 95 -50 0.02 190 -0.9 28 30 60 | 406 280 | $\begin{aligned} & 454 \\ & 300 \end{aligned}$ | $\begin{aligned} & \text { ns typ } \\ & \text { ns max } \\ & \text { ns typ } \\ & \text { ns max } \\ & \text { pC typ } \\ & \text { dB typ } \\ & \text { \% typ } \\ & \text { MHz typ } \\ & \text { dB typ } \\ & \text { pF typ } \\ & \text { pF typ } \\ & \text { pF typ } \\ & \hline \end{aligned}$ | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ <br> $\mathrm{V}_{\mathrm{s}}=8 \mathrm{~V}$; see Figure 24 <br> $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ <br> $\mathrm{V}_{\mathrm{s}}=8 \mathrm{~V}$; see Figure 24 <br> $V_{s}=6 \mathrm{~V}, \mathrm{R}_{\mathrm{s}}=0 \Omega, \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}$; see <br> Figure 25 <br> $R \mathrm{~L}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; see <br> Figure 20 <br> $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, 6 \mathrm{~V} p-\mathrm{p}, \mathrm{f}=20 \mathrm{~Hz}$ to <br> 20 kHz ; see Figure 22 <br> $R_{L}=50 \Omega, C_{L}=5 \mathrm{pF}$; see Figure 23 <br> $R_{L}=50 \Omega, C_{L}=5 \mathrm{pF}, f=1 \mathrm{MHz}$; see <br> Figure 23 $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=6 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{s}}=6 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{S}}=6 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ |
| POWER REQUIREMENTS <br> IdD <br> $V_{D D}$ | $\begin{aligned} & 40 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 9 / 40 \end{aligned}$ | $\mu A$ typ <br> $\mu \mathrm{A}$ max <br> $V$ min/V max | $V_{D D}=13.2 \mathrm{~V}$ <br> Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ $\mathrm{GND}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{ss}}=0 \mathrm{~V}$ |

[^2]
## 36 V SINGLE SUPPLY

$\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}$, unless otherwise noted.
Table 4.

| Parameter | $25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH <br> Analog Signal Range On Resistance, Ron <br> On-Resistance Flatness, Rflat (ON) | $\begin{aligned} & 7 \\ & 9 \\ & 1.8 \\ & 2.6 \end{aligned}$ | 11 $3$ | 0 V to $\mathrm{V}_{\mathrm{DD}}$ <br> 13 <br> 3.5 |  | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V} \text { to } 30 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA} \text {; see }$ <br> Figure 19 $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=32.4 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V} \text { to } 30 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=-10 \mathrm{~mA} \end{aligned}$ |
| LEAKAGE CURRENTS <br> Source Off Leakage, Is (Off) <br> Drain Off Leakage, lo (Off) <br> Channel On Leakage, $\mathrm{I}_{\mathrm{D}}(\mathrm{On}), \mathrm{I}_{\mathrm{s}}(\mathrm{On})$ | $\begin{aligned} & \pm 0.1 \\ & \pm 0.5 \\ & \pm 0.1 \\ & \pm 0.5 \\ & \pm 0.2 \\ & \pm 1 \end{aligned}$ | $\pm 2$ $\pm 2$ $\pm 8$ | $\begin{aligned} & \pm 20 \\ & \pm 20 \\ & \pm 40 \end{aligned}$ | nA typ <br> nA max <br> nA typ <br> nA max <br> nA typ <br> nA max | $\begin{aligned} & V_{D D}=+39.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=1 \mathrm{~V} \text { to } 30 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=30 \mathrm{~V} \text { to } 1 \mathrm{~V} \text {; see } \end{aligned}$ <br> Figure 18 <br> $\mathrm{V}_{\mathrm{S}}=1 \mathrm{~V}$ to $30 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}==30 \mathrm{~V}$ to 1 V ; see Figure 18 $V_{S}=V_{D}=1 \mathrm{~V} \text { to } 30 \mathrm{~V} \text {; see Figure } 21$ |
| DIGITAL INPUTS <br> Input High Voltage, $\mathrm{V}_{\mathrm{INH}}$ Input Low Voltage, VINL Input Current, $\mathrm{I}_{\mathrm{NL}}$ or $\mathrm{I}_{\mathrm{INH}}$ <br> Digital Input Capacitance, $\mathrm{C}_{\mathrm{IN}}$ | $\begin{aligned} & 0.002 \\ & 6 \end{aligned}$ |  | $\begin{gathered} 2.0 \\ 0.8 \\ \pm 0.1 \end{gathered}$ | V min <br> $\checkmark$ max <br> $\mu \mathrm{A}$ typ <br> $\mu \mathrm{A}$ max <br> pF typ | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\text {DD }}$ |
| ```DYNAMIC CHARACTERISTICS` ton toff Charge Injection, QiN, Off Isolation Total Harmonic Distortion + Noise (THD + N) -3 dB Bandwidth Insertion Loss Cs (Off) CD (Off) CD (On), CS (On)``` | 160 187 180 213 255 -50 0.01 170 -0.55 26 28 65 | 212 221 | $\begin{aligned} & 230 \\ & 225 \end{aligned}$ | ns typ ns max ns typ ns max pC typ dB typ \% typ MHz typ dB typ pF typ pF typ pF typ | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ <br> $\mathrm{V}_{\mathrm{s}}=18 \mathrm{~V}$; see Figure 24 <br> $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ <br> $\mathrm{V}_{\mathrm{s}}=18 \mathrm{~V}$; see Figure 24 <br> $V_{S}=18 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=0 \Omega, \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}$; see <br> Figure 25 <br> $R \mathrm{~L}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; see <br> Figure 20 <br> $R_{L}=1 \mathrm{k} \Omega, 18 \mathrm{~V} p-\mathrm{p}, \mathrm{f}=20 \mathrm{~Hz}$ to <br> 20 kHz ; see Figure 22 <br> $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$; see Figure 23 <br> $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; <br> see Figure 23 $\begin{aligned} & \mathrm{V}_{\mathrm{s}}=18 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{s}}=18 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{s}}=18 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ |
| POWER REQUIREMENTS Ido $V_{D D}$ | $\begin{aligned} & 80 \\ & 100 \end{aligned}$ |  | $\begin{aligned} & 130 \\ & 9 / 40 \end{aligned}$ | $\mu \mathrm{A}$ typ <br> $\mu \mathrm{A}$ max <br> $V \min / V \max$ | $\begin{aligned} & \mathrm{V} \mathrm{VD}=39.6 \mathrm{~V} \\ & \text { Digital inputs }=0 \mathrm{~V} \text { or } \mathrm{VDD} \\ & \\ & \mathrm{GND}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V} \end{aligned}$ |

[^3]
#### Abstract

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## CONTINUOUS CURRENT PER CHANNEL, S OR D

Table 5.

| Parameter | $\mathbf{2 5}{ }^{\circ} \mathbf{C}$ | $\mathbf{8 5}^{\circ} \mathbf{C}$ | $\mathbf{1 2 5}{ }^{\circ} \mathbf{C}$ | Unit | Test Condition/Comments |
| :--- | :--- | :--- | :--- | :--- | :--- |
| CONTINUOUS CURRENT, S OR D |  |  |  |  | MSOP $\left(\theta_{\mathrm{JA}}=133.1^{\circ} \mathrm{C} / \mathrm{W}\right)$ |
| $\mathrm{V}_{\mathrm{DD}}=+15 \mathrm{~V}, \mathrm{~V}_{S S}=-15 \mathrm{~V}$ | 171 | 116 | 79 | mA maximum |  |
| $\mathrm{V}_{\mathrm{DD}}=+20 \mathrm{~V}, \mathrm{~V}_{S S}=-20 \mathrm{~V}$ | 177 | 120.5 | 81 | mA maximum |  |
| $\mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V}$ | 139 | 99 | 70 | mA maximum |  |
| $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V}$ | 174 | 118 | 81 | mA maximum |  |

## ABSOLUTE MAXIMUM RATINGS

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted.
Table 6.

| Parameter | Rating |
| :---: | :---: |
| $\mathrm{V}_{\text {D }}$ to $\mathrm{V}_{5 S}$ | 48 V |
| $V_{\text {D }}$ to GND | -0.3 V to +48 V |
| $V_{\text {ss }}$ to GND | +0.3 V to -48 V |
| Analog Inputs ${ }^{1}$ | $V_{S S}-0.3 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V} \text { or }$ 30 mA , whichever occurs first |
| Digital Inputs ${ }^{1}$ | $\mathrm{V}_{S S}-0.3 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V}$ or 30 mA , whichever occurs first |
| Peak Current, S or D Pin | 630 mA (pulsed at 1 ms , 10\% duty cycle maximum) |
| Continuous Current, S or $\mathrm{D}^{2}$ | Data + 15\% |
| Temperature Range |  |
| Operating | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Storage | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Junction Temperature | $150^{\circ} \mathrm{C}$ |
| Thermal Impedance, $\theta_{\mathrm{JA}}$ |  |
| 8-Lead MSOP (4-Layer Board) | $133.1{ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Reflow Soldering Peak Temperature, Pb Free | As per JEDEC J-STD-020 |
| Human Body Model (HBM) ESD | 8 kV |

[^4]Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
Only one absolute maximum rating can be applied at any one time.

## ESD CAUTION

|  | ESD (electrostatic discharge) sensitive device. <br> Charged devices and circuit boards can discharge <br> without detection. Although this product features <br> patented or proprietary protection circuitry, damage <br> may occur on devices subjected to high energy ESD. <br> Therefore, proper ESD precautions should be taken to <br> avoid performance degradation or loss of functionality. |
| :--- | :--- |

## Data Sheet

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



Figure 2. Pin Configuration

Table 7. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
| :--- | :--- | :--- |
| 1 | S | Source Terminal. This pin can be an input or output. |
| 2 | NC | No Connect. Not internally connected. |
| 3 | GND | Ground (O V) Reference. |
| 4 | VDD | Most Positive Power Supply Potential. |
| 5 | NC | No Connect. Not internally connected. |
| 6 | IN | Logic Control Input. |
| 7 | VSS | Most Negative Power Supply Potential. |
| 8 | D | Drain Terminal. This pin can be an input or output. |

Table 8. Truth Table

| IN | Switch Condition |
| :--- | :--- |
| 1 | On |
| 0 | Off |

## ADG5401

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 3. On Resistance as a Function of $V_{S}, V_{D}$ (Dual Supply)


Figure 4. On Resistance as a Function of $V_{s,} V_{D}$ (Single Supply)


Figure 5. On Resistance as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, $\pm 15$ V Dual Supply


Figure 6. On Resistance as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, $\pm 20$ V Dual Supply


Figure 7. On Resistance as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, 12 V Single Supply


Figure 8. On Resistance as a Function of $V_{s}\left(V_{D}\right)$ for Different Temperatures, 36 V Single Supply


Figure 9. Leakage Currents as a Function of Temperature, $\pm 15$ V Dual Supply


Figure 10. Leakage Currents as a Function of Temperature, $\pm 20$ V Dual Supply


Figure 11. Leakage Currents as a Function of Temperature, 12 V Single Supply


Figure 12. Leakage Currents as a Function of Temperature, 36 V Single Supply


Figure 13. Off Isolation vs. Frequency


Figure 14. Charge Injection vs. Source Voltage (Vs)


Figure 15. THD + N vs. Frequency


Figure 16. Bandwidth


Figure 17. $t_{\text {Transition }}$ Times vs. Temperature

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## TEST CIRCUITS



Figure 18. Off Leakage


Figure 19. On Resistance

Figure 20. Off Isolation



Figure 21. On Leakage


Figure 22. $T H D+N$


Figure 23. Bandwidth


Figure 24. Switching Times, ton and toff


## TERMINOLOGY

## $I_{D D}$

IDD represents the positive supply current.
Iss
Iss represents the negative supply current.

## $V_{D}, V_{s}$

$V_{D}$ and $V_{S}$ represent the analog voltage on Terminal $D$ and Terminal S, respectively.

## $\mathrm{R}_{\text {on }}$

Ron is the ohmic resistance between Terminal D and Terminal S.

## $\mathbf{R}_{\text {fLat (ON) }}$

$\mathrm{R}_{\text {FLat (ON) }}$ represents the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.
$I_{s}$ (Off)
$\mathrm{I}_{\mathrm{s}}$ (Off) is the source leakage current with the switch off.
$\mathrm{I}_{\mathrm{D}}$ (Off)
$\mathrm{I}_{\mathrm{D}}$ (Off) is the drain leakage current with the switch off.
$\mathrm{I}_{\mathrm{D}}(\mathrm{On}), \mathrm{I}_{\mathrm{S}}(\mathbf{O n})$
$\mathrm{I}_{\mathrm{D}}(\mathrm{On})$ and $\mathrm{I}_{\mathrm{S}}(\mathrm{On})$ represent the channel leakage currents with the switch on.
$V_{\text {INL }}$
$V_{\text {INL }}$ is the maximum input voltage for Logic 0 .
$V_{\text {InH }}$
$\mathrm{V}_{\text {INH }}$ is the minimum input voltage for Logic 1.

## Iinl, $\mathbf{I}_{\text {INH }}$

$\mathrm{I}_{\mathrm{INL}}$ and $\mathrm{I}_{\mathrm{INH}}$ represent the low and high input currents of the digital inputs.
$\mathrm{C}_{\mathrm{D}}$ (Off)
$C_{D}$ (Off) represents the off switch drain capacitance, which is measured with reference to ground.

Cs (Off)
Cs (Off) represents the off switch source capacitance, which is measured with reference to ground.
$\mathrm{C}_{\mathrm{D}}(\mathrm{On}), \mathrm{C}_{\mathrm{s}}(\mathrm{On})$
$C_{D}(\mathrm{On})$ and $C_{S}(\mathrm{On})$ represent the on switch capacitances, which are measured with reference to ground.
$\mathrm{C}_{\mathrm{IN}}$
$\mathrm{C}_{\mathrm{IN}}$ represents digital input capacitance.
ton
$t_{\text {on }}$ represents the delay time between the $50 \%$ and $90 \%$ points of the digital input and switch on condition.
$t_{\text {off }}$
toff represents the delay time between the $50 \%$ and $90 \%$ points of the digital input and switch off condition.

## Off Isolation

Off isolation is a measure of unwanted signal coupling through an off channel.

## Charge Injection

Charge injection is a measure of the glitch impulse transferred from the digital input to the analog output during switching.

## Bandwidth

Bandwidth is the frequency at which the output is attenuated by 3 dB from its dc value.
Total Harmonic Distortion + Noise (THD + N)
The ratio of the harmonic amplitude plus noise of the signal to the fundamental is represented by THD +N .

## APPLICATIONS INFORMATION

The ADG54xx family of switches and multiplexers provide a robust solution for instrumentation, industrial, aerospace, and other harsh environments that are prone to latch-up, which is an undesirable high current state that can lead to device failure and persists until the power supply is turned off. The ADG5401 high voltage switch allows single-supply operation from 9 V to 40 V and dual-supply operation from $\pm 9 \mathrm{~V}$ to $\pm 22 \mathrm{~V}$. The ADG5401 (as well as other select devices within this family) achieves an 8 kV human body model ESD rating, which provides a robust solution, eliminating the need for separate protection circuitry designs in some applications.

## TRENCH ISOLATION

In the ADG5401, an insulating oxide layer (trench) is placed between the NMOS and the PMOS transistors of each CMOS switch. Parasitic junctions, which occur between the transistors in junction-isolated switches, are eliminated, and the result is a


Figure 26. Trench Isolation

In junction isolation, the N and P wells of the PMOS and NMOS transistors form a diode that is reverse-biased under normal operation. However, during overvoltage conditions, this diode can become forward-biased. The two transistors form a silicon-controlled rectifier (SCR) type circuit, causing a significant amplification of the current that, in turn, leads to latch-up. With trench isolation, this diode is removed, and the result is a latch-up immune switch.

## Data Sheet

## OUTLINE DIMENSIONS


gure 27. 8-Lead Mini Small Outline Package [MSOP] (RM-8)
Dimensions shown in millimeters

ORDERING GUIDE

| Model $^{1}$ | Temperature Range | Package Description | Package Option | Branding |
| :--- | :--- | :--- | :--- | :--- |
| ADG5401BRMZ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead Mini Small Outline Package $[\mathrm{MSOP}]$ | $\mathrm{RM}-8$ | S 2 M |
| ADG5401BRMZ-RL7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead Mini Small Outline Package $[\mathrm{MSOP}]$ | RM-8 | S2M |

[^5]NOTES
$\square$
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NOTES

## NOTES


[^0]:    ${ }^{1}$ Guaranteed by design; not subject to production test

[^1]:    ${ }^{1}$ Guaranteed by design; not subject to production test.

[^2]:    ${ }^{1}$ Guaranteed by design; not subject to production test.

[^3]:    ${ }^{1}$ Guaranteed by design; not subject to production test.

[^4]:    ${ }^{1}$ Overvoltages at the IN, S, and D pins are clamped by internal diodes. Limit current to the maximum ratings given.
    ${ }^{2}$ See Table 5.

[^5]:    ${ }^{1} \mathrm{Z}=$ RoHS Compliant Part.

